NSN 5961-01-303-4840

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Semiconductor Material:
Gallium arsenide phosphide
Voltage Rating In Volts Per Characteristic:
5.0 collector supply voltage
Current Rating Per Characteristic:
1.00 milliamperes source cutoff current and 20.00 milliamperes source cutoff current preset
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig: